

JAPANESE JOURNAL OF APPLIED PHYSICS

Volume 49, Number 3, March 2010 [Issue 1 of 2]

Invited Review Papers

- 030001 **Radiation Chemistry in Chemically Amplified Resists (19 pages)**
Takahiro Kozawa, Seiichi Tagawa

Rapid Communications

- 030201 **Improvement in Ferroelectric Fatigue Endurance of Poly(methyl metacrylate)-Blended Poly(vinylidene fluoride-trifluoroethylene) (3 pages)**
Joo-Won Yoon, Sung-Min Yoon, Hiroshi Ishiwara
- 030202 **LiF/Al Base Electrodes in Vertical Metal-Base Organic Transistors for Heat-Treatment-Free Process (3 pages)**
Fumito Suzuki, Ken-ichi Nakayama, Yong-Jin Pu, Masaaki Yokoyama, Junji Kido
- 030203 **Low-Voltage Pentacene Field-Effect Transistors Fabricated on High-Dielectric-Constant Strontium Titanate Insulator (3 pages)**
Hu Yan, Toshihiko Jo, Hidenori Okuzaki
- 030204 **A Proposal of a Novel Gain Profile Model of Multi-Quantum-Well Semiconductor Optical Amplifiers (3 pages)**
Satoshi Shimizu, Hiroyuki Uenohara
- 030205 **Optimization of Active Layer Thickness in Planar Organic Solar Cells via Optical Simulation Methods (3 pages)**
Patrick Boland, Gon Namkoong
- 030206 **LiNbO₃ Waveguide Quasi-Phase-Matched Highly Nondegenerate Twin Photon Generation Device for Heralded Single Photon Source (3 pages)**
Shozo Kajita, Masatoshi Fujimura, Toshiaki Suhara
- 030207 **Development of a Total Reflection Zone Plate for Hard X-ray Focusing (3 pages)**
Takuya Tsuji, Hidekazu Takano, Takahisa Koyama, Yoshiyuki Tsusaka, Yasushi Kagoshima
- 030208 **New Approach to Enhance Contrast Ratio at Normal Incidence by Controlling the Retardation of Optical Compensation Film in Vertically Aligned Liquid Crystal Displays (3 pages)**
Makoto Ishiguro, Megumi Sekiguchi, Yukito Saitoh
- 030209 **Fast Eight-Domain Patterned Vertical Alignment Mode with Reactive Mesogen for a Single-Transistor-Driving (3 pages)**
You-Jin Lee, Soo In Jo, Jae-Hoon Kim, Chang-Jae Yu
- 030210 **Optoelectronic Characteristics of HgSe Nanoparticle Films Spin-Coated on Flexible Plastic Substrates (3 pages)**
Jaewon Jang, Kyoungah Cho, Kwangsub Byun, Wan-Shick Hong, Sangsig Kim
- 030211 **Highly Stacked and High-Quality Quantum Dots Fabricated by Intermittent Deposition of InGaAs (3 pages)**
Takeyoshi Sugaya, Takeru Amano, Masahiko Mori, Shigeru Niki, Michio Kondo
- 030212 **Stability and Indium Incorporation Processes on In_{0.25}Ga_{0.75}N Surfaces under Growth Conditions: First-Principles Calculations (3 pages)**
Toru Akiyama, Tomoki Yamashita, Kohji Nakamura, Tomonori Ito
- 030213 **Characteristics of Internal Inductively Coupled Plasma Source for Ultralarge-Area Plasma Processing (3 pages)**
Jong Hyuk Lim, Gwang Ho Gweon, Seung Pyo Hong, Kyong Nam Kim, Yi Yeon Kim, Geun Young Yeom

Regular Papers

Semiconductors, dielectrics, and organic materials

- 031101 **Highly Transparent and High Haze Bilayer Al-Doped ZnO Thin Film Employing Oxygen-Controlled Seed Layer (5 pages)**
Dong-Won Kang, Seung-Hee Kuk, Kwang-Sun Ji, Seh-Won Ahn, Min-Koo Han

(Continued on third cover)

- 031102 **Investigation of Interface Formed between Top Electrodes and Epitaxial NiO Films for Bipolar Resistance Switching (4 pages)**
 Seung Ran Lee, Hoon Min Kim, Jung Hoon Bak, Yun Daniel Park, Kookrin Char, Hong Woo Park, Deok-Hwang Kwon, Miyoung Kim, Dong-Chirl Kim, Sunae Seo, Xiang-Shu Li, Gyeong-Su Park, Ranju Jung
- 031103 **Etching Characteristics of In_2O_3 and SnO_2 Thin Films in an Inductively Coupled HBr/Ar Plasma: Effects of Gas Mixing Ratio and Bias Power (5 pages)**
 Kwang-Ho Kwon, Alexander Efremov, Moonkeun Kim, Nam Ki Min, Jaehwa Jeong, Kwangsoo Kim
- 031104 **Investigation of Bending Stability of Amorphous Zn-In-Sn-O Thin Films on Flexible Poly(ether sulfone) Substrates (5 pages)**
 Gi-Seok Heo, In-Gi Gim, Hyun-Kee Lee, Jeong-Hwan Song, Tae-Won Kim
- 031105 **In-situ X-ray Absorption Fine Structure Study of TiO_2 Nanoparticles under Ultraviolet Light (4 pages)**
 Jong-Sul Jeon, Byung-Hyuk Kim, Chang-In Park, Soo-Young Seo, Changha Kwak, Seon-Hyo Kim, Sang-Wook Han
- 031106 **Excitation Processes of Photoluminescence and Origin of Absorption Peak Shift in ZnO Porous Films Modified with Eu Ions (4 pages)**
 Aishi Yamamoto, Masashi Noritake, Yoshiyuki Harumoto, Hisao Yanagi, Kazuho Mizuta, Tsukasa Yoshida
- 031201 **Temperature Limitations of Quantum Hall Far-Infrared Photodetectors (3 pages)**
 Jeng-Chung Chen, Jingbin Zhang, Cheng-Chung Chi, Takeji Ueda, Susumu Komiyama
- 031202 **Band Offsets and Photoluminescence Thermal Quenching in Mid-Infrared Emitting GaInAsSb Quantum Wells with Quinary AlGaNAsSb Barriers (4 pages)**
 Grzegorz Sęk, Marcin Motyka, Krzysztof Ryczko, Filip Janiak, Jan Misiewicz, Sofiane Belahsene, Guilhem Boissier, Yves Rouillard
- 031301 **Effects of Bulk Microdefects and Metallic Impurities on p-n Junction Leakage Currents in Silicon (7 pages)**
 Kwang-Salk Kim, Byeong-sam Moon, Hee-Bok Kang, Jea-gun Park, Bo-Young Lee
- 031302 **Formation of p-Type Semiconducting Ultrananocrystalline Diamond/Hydrogenated Amorphous Carbon Composite Films by Boron Doping (4 pages)**
 Shinya Ohmagari, Tsuyoshi Yoshitake, Akira Nagano, Ryota Ohtani, Hiroyuki Setoyama, Eiichi Kobayashi, Takeshi Hara, Kunihito Nagayama
- 031501 **First-Principles Study of Structural Trend of $BiMO_3$ and $BaMO_3$: Relationship between Tetragonal or Rhombohedral Structure and the Tolerance Factors (6 pages)**
 Kaoru Miura, Tatsuo Furuta
- 031502 **Metalorganic Chemical Vapor Deposition of Al_2O_3 Thin Films from Dimethylaluminumhydride and O_2 (7 pages)**
 Gang He, Xiaoliang Wang, Masaharu Oshima, Yukihiro Shimogaki
- 031601 **Aqueous Dispersion of J-Aggregates Prepared by Polyion Complexation and Its Two-Photon Excited Fluorescence Property (6 pages)**
 Noritaka Kato, Yukinobu Katayama, Haruyuki Semba, Ken-ichi Iimura

Photonics, quantum electronics, optics, and spectroscopy

- 032101 **High-Brightness 350 nm Ultraviolet InAlGaN Light Emitting Diodes on Si(111) Substrate with Transparent AlN/AlGaN Buffer Structure (5 pages)**
 Yasuyuki Fukushima, Tetsuzo Ueda
- 032301 **Pentacene:Fullerene Multilayer-Heterojunction Organic Photovoltaic Cells Fabricated by Alternating Evaporation Method (7 pages)**
 Jun Sakai, Tetsuya Taima, Toshihiro Yamanari, Yuji Yoshida, Akihiko Fujii, Masanori Ozaki
- 032401 **Study of Ion-Beam-Induced Damage and Luminescence Properties in Terbium-Implanted AlGaN (5 pages)**
 Ji-Ho Park, Akihiro Wakahara, Hiroshi Okada, Yuzo Furukawa, Yong-Tae Kim, Ho-Jung Chang, Jonghan Song, Sangwon Shin, Jong-Han Lee, Shin-ichiro Sato, Takeshi Ohshima
- 032402 **Generation and Propagation of Sub-Terahertz Pulse Signal Using Waveguide-Integrated InP/InGaAs Uni-Traveling-Carrier Photodiode (5 pages)**
 Hiroshi Ito, Hiroshi Yamamoto, Tomofumi Furuta, Tadao Ishibashi
- 032501 **New Weighting Function Designed for Low-Crosstalk, Small Length Mismatched Optical Coupler (6 pages)**
 Chi-Feng Chen

(Continued on preceding page)

(Continued)

- 032502 **Diffraction Properties in Polarization Holography Written by Elliptical Polarized Light** (4 pages)
Hiroshi Ono, Manabu Nakamura, Akira Emoto, Nobuhiro Kawatsuki
- 032601 **Growth, Optical Properties, and Scintillation Light Yield of CaF₂:Ce Crystals with Different Ce Concentration** (5 pages)
Takayuki Yanagida, Kyoung Jin Kim, Kei Kamada, Yuui Yokota, Shuji Maeo, Akira Yoshikawa, Noriaki Kawaguchi, Kentaro Fukuda, Nobuhiko Sarukura, Valery Chani
- 032602 **Amplified Spontaneous Emission from the Monomer of a Conjugate Polymer by Energy Transfer Process** (4 pages)
Mohamad AlSalhi
- 032701 **Erbium-Doped All-Fiber Green Up-Conversion Amplified Emission in Silica-Based Fiber System** (4 pages)
Hong-Xi Tsao, Shih-Ting Lin, Hsin-Chia Su, Ji-Bin Horng, Jinn-Kong Sheu
- 032702 **Numerical Investigation of Method of Reconstructing Gain-Switched Picosecond Pulses from Laser Diodes without Autocorrelation Measurements** (7 pages)
Kenji Wada, Tetsuya Matsuyama, Daisuke Noritake, Hidetoshi Fukui, Shinji Koyama, Hiromichi Horinaka
- 032703 **Carrier-Envelope Phase Control of Few-Cycle Parametric Chirped-Pulse Amplifier** (4 pages)
Shunsuke Adachi, Nobuhisa Ishii, Yohei Kobayashi, Yutaka Nomura, Jiro Itatani, Teruto Kanai, Shuntaro Watanabe

Spintronics, superconductivity, and strongly correlated materials

- 033001 **Structure and Magnetic Properties of Mn-Implanted ZnO Films** (4 pages)
Xianwen Ke, Changwei Zou, Ming Li, Chuangsheng Liu, Liping Guo, Dejun Fu
- 033002 **Investigation of Spin-Dependent Transport Properties and Spin-Spin Interactions in a Copper-Phthalocyanine-Cobalt Nanocomposite System** (4 pages)
Zhenyao Tang, Shinichi Tanabe, Daiki Hatanaka, Takayuki Nozaki, Teruya Shinjo, Shigemi Mizukami, Yasuo Ando, Yoshishige Suzuki, Masashi Shiraishi
- 033003 **Deconvolution of Transmission Mössbauer Spectra Using Conjugate Gradient Method** (5 pages)
Ryuji Kato, Yoshihori Tamada, Teruo Ono, Saburo Nasu
- 033004 **Tunable Microwave Filters and Phase Shifters Based on Ferromagnetic/Dielectric Multilayer Waveguides** (6 pages)
Jiashu Zhang, Jinzhu Zhao, Ruwen Peng, Jia Li, Ruili Zhang, Mu Wang
- 033101 **Growth and Anisotropic Properties of RBa₂Cu₃O_x Single-Crystal Whiskers** (4 pages)
Masanori Nagao, Satoshi Watauchi, Isao Tanaka, Takashi Okutsu, Yoshihiko Takano, Takeshi Hatano, Hiroshi Maeda

Device physics

- 034001 **Quantum Mechanical Effects on the Threshold Voltage of Double-Gate Metal-Oxide-Semiconductor Field-Effect Transistors** (4 pages)
Guang-Xi Hu, Ran Liu, Zhi-Jun Qiu, Ling-Li Wang, Ting-Ao Tang
- 034201 **Improved Radio Frequency Power Characteristics of Complementary Metal-Oxide-Semiconductor-Compatible Asymmetric-Lightly-Doped-Drain Metal-Oxide-Semiconductor Transistor** (5 pages)
Tsui Chang, Hsuan-ling Kao, Y. J. Chen, Albert Chin
- 034202 **Evaluation of Relfilled Channel Regions in 4H-SiC Buried Gate Static Induction Transistors** (4 pages)
Akio Takatsuka, Yasunori Tanaka, Koji Yano, Tsutomu Yatsuo, Kazuo Arai
- 034203 **Low Frequency Noise Characterization in Metal Oxide Semiconductor Field Effect Transistor Based Charge Transfer Device at Room and Low Temperatures** (4 pages)
Vipul Singh, Hiroshi Inokawa, Tetsuo Endoh, Hiroaki Satoh

Nanoscale science and technology

- 035001 **Formation of Si Nanocrystallites in Al-Added Amorphous Si Films by Electron Beam Irradiation** (4 pages)
Jae-Hyun Shim, Nam-Hee Cho, Jin-Gyu Kim, Youn-Joong Kim
- 035002 **Optimization of Interface Resistance between Carbon Nanotubes and Probe-Shaped Titanium Wire** (3 pages)
Hiroyuki Tomimoto, Tomonobu Nakayama
- 035003 **Simultaneous Size Control of Microcapsule and Its Nanopores Using Polymer Concentration** (4 pages)
Jemyung Cha, Eun Ho Jeong, Arakawa Takahiro, Kyung Chun Kim, Shuich Shoji, Jeung Sang Go

(Continued on preceding page)

(Continued)

- 035201 Double Patterning Analysis Method by Emulation Using a Double-Exposure Technique (6 pages)
Junji Miyazaki, Nobuhito Toyama, Akira Kawai

Crystal growth, surfaces, interfaces, thin films, and bulk materials

- 035501 Gettering Efficiency of Si(110)/Si(100) Directly Bonded Hybrid Crystal Orientation Substrates (6 pages)
Tatsuhiko Aoki, Hiroaki Kariyazaki, Koji Sueoka, Eiji Toyoda, Koji Izunome
- 035502 Surface Evolution of GaP Grown on Si Substrates Using Metalorganic Vapor Phase Epitaxy (5 pages)
Yasushi Takano, Tatsuya Takagi, Yuuki Matsuo, Shunro Fuke
- 035701 Effects of the AlN Interlayer on the Distribution and Mobility of Two-Dimensional Electron Gas
in AlGaN/AlN/GaN Heterojunctions (4 pages)
Weiguo Hu, Bei Ma, Dabing Li, Reina Miyagawa, Hideto Miyake, Kazumasa Hiramatsu
- 035702 Local Density of States of Partially Oxidized Ag(110) Surfaces Observed Using Scanning Tunneling
Microscope Light-Emission Spectroscopy (6 pages)
Yoichi Uehara, Suketsue Ushioda
- 035801 Deposition of Amorphous Zinc Indium Tin Oxide and Indium Tin Oxide Films on Flexible
Poly(ether sulfone) Substrate Using RF Magnetron Co-sputtering System (5 pages)
Gi-Seok Heo, Yuji-Matsumoto, In-Gi Gim, Jong-Woon Park, Gwang-Young Kim, Tae-Won Kim

Plasmas, applied atomic and molecular physics, and applied nuclear physics

- 036001 Evaluation of Electron Energy Distribution Function in Microwave Discharge Plasmas by Spectroscopic
Diagnostics with Collisional Radiative Model (14 pages)
Jun Mizuuchi, Takeshi Sakamoto, Haruaki Matsuura, Hiroshi Akatsuka
- 036101 Self-Calibrated Measurement of Ion Flow Using a Fine Multi-hole Directional Langmuir Probe (6 pages)
Kenichiro Terasaka, Shinji Yoshimura, Tetsushi Katahira,
Kohei Ogiwara, Mitsutoshi Aramaki, Masayoshi Y. Tanaka

Device processing, fabrication and measurement technologies, and instrumentation

- 036501 Gate Overlap Optimization and Performance Variation for Thin-Film Transistors with Source/Drain Edge
Waviness (5 pages)
Jaewook Jeong, Yongtaek Hong
- 036502 Line Edge Roughness Reduction Using Resist Reflow Process for 22 nm Node Extreme Ultraviolet
Lithography (4 pages)
In Wook Cho, Hyunsu Kim, Jee-Hye You, Hye-Keun Oh
- 036503 Evaluation of Damage Layer in an Organic Film with Irradiation of Energetic Ion Beams (5 pages)
Masaki Hada, Sachi Ibuki, Satoshi Ninomiya, Toshio Seki, Takaaki Aoki, Jiro Matsuo
- 036504 Effects of Si/Ni Composition Ratio of Ni_xSi_y Gate Electrode and Hf/Si Composition Ratio of Hf-Based
High-k Insulator on Threshold Voltage Controllability and Mobility of Metal–Oxide–Semiconductor Field-
Effect Transistors (7 pages)
Masayuki Terai, Takashi Hase, Kentaro Shibahara, Hirohito Watanabe
- 036505 Planar Metal–Oxide–Semiconductor Field-Effect Transistors with Raised Source and Drain Extensions
Fabricated by *In situ* Boron-Doped Selective Silicon Epitaxy (4 pages)
Yoshiaki Kikuchi, Yasushi Tateshita, Yuki Miyanami, Hitoshi Wakabayashi, Yukio Tagawa, Naoki Nagashima
- 036506 Diffusion Control Using Matrix Change during Chemical Reaction for Inducing Anisotropic Diffusion in
Chemically Amplified Resists (5 pages)
Takahiro Kozawa, Hiroaki Oizumi, Toshiro Itani, Seiichi Tagawa
- 036507 Optimal Channel Ion Implantation for High Memory Margin of Capacitor-Less Memory Cell Fabricated on
Fully Depleted Silicon-on-Insulator (4 pages)
Seong-Je Kim, Jung-Mi Oh, Tae-Hun Shim, Jea-Gun Park

Cross-disciplinary areas

- 037001 Magnification Embossed Radiography Utilizing Image-Shifting Subtraction Program (7 pages)
Akihiro Osawa, Manabu Watanabe, Eiichi Sato, Hiroshi Matsukiyo, Toshiyuki Enomoto, Jiro Nagao,
Purkhett Abderyim, Katsu Aizawa, Etsuro Tanaka, Hidezo Mori, Toshiaki Kawai,
Akira Ogawa, Kiyomi Takahashi, Shigehiro Sato, Jun Onagawa

(Continued on preceding page)

(Continued)

Brief Notes

- 038001 **Negative Oxide Charge in Thermally Oxidized Cr-Contaminated n-Type Silicon Wafers (2 pages)**
Hiromi Shimizu, Sadayoshi Shimada, Masanori Ikeda
- 038002 **Measurement of Radiation Frequency of Gyrotron by GaAs Schottky Barrier Diodes Coupled with Thin-Film Slot Antenna (2 pages)**
Kosuke Hayashi, Takashi Furuya, Takashi Tachiki, Takashi Uchida, Toshitaka Idehara, Yoshizumi Yasuoka
- 038003 **Double Self Quotient Image Based Image Flattening for Defect Detection in Thin Film Transistor Liquid Crystal Display Panel (2 pages)**
Young-Chul Song, Se-Yun Kim, Kil-Houm Park
- 038004 **Quasi-Two-Dimensional Network Structures Formed by Tin Oxide Nanoparticles at Air/Solid interfaces (2 pages)**
Atsumi Wakabayashi, Tomohiro Ogawa, Takao Yamamoto, Toshiaki Dobashi
- 038005 **Electroluminescence Analysis by Tilt Polish Technique of InP-Based Semiconductor Lasers (2 pages)**
Hiroyuki Ichikawa, Kouichi Sasaki, Kotaro Hamada, Akira Yamaguchi

Errata

- 039201 **Erratum: "A Reliable Nonvolatile Memory Using Alloy Nanodot Layer with Extremely High Density" [48 (2009) 106505] (1 page)**
Yun Heub Song, Ji Cheol Bea, Kang Wook Lee, Gae-Hun Lee, Tetsu Tanaka, Mitsumasa Koyanagi

Fig. 6. SEM and AFM images of a scanned surface.

is shown in Fig. 3. The Al₂O₃ insulating sheet was placed on a rotating stage, and the rotating speed was set in synchro with experiments. When the back surface of the base was scanned in a tilt with the green arrow-right, the tilt angle was estimated to be 110–13°. The scanning rate was approximately 30 s. Then, the wafers were rinsed, and the base was separated from the wafer. The base was presented on the green-yellow red position under both tips. The scanning electron microscope (SEM) had successive image control after the tilting tilt process was over (Fig. 4). A polished surface and a surface with remaining profile of the recessed area were obtained. Then we carried out wire bonding to stick the return to the base. The SEM image was magnified on a scale of $\times 25$ and denoted using an infrared microscope. The SEM image of an infrared base is shown in Fig. 5. Subsequently, after 1 h, was observed. There might

be some effect of the temperature on the scanning process because no scanning was conducted when the temperature was above 100 °C. Although the scanning process time was a couple of hours, the tilt angle difference was less than 1.5°. The short scanning time and low voltage of the positive electrode were the main reason for using the polish technique. This technique can be applied to other materials, such as Si, GaN, and AlN.

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